



SiHSi 2x0,35 qmm

Construction

- Conductor: Tin plated copper
- Strand structure: 2 x 0,35 qmm (11x 0,20 mm)
- Core: Silicone rubber, diameter: 3,20 +/- 0,10mm, cores bunched
- Sheath: Silicone rubber, outer diameter 8,00 +/- 0,30mm

Technical Data

- Nominal voltage: 1500 V DC
- Test voltage: 4000 V AC
- Operating temperature: -50°C to +180°C

Article number: 822602S359

- Further formats available on request
- All data and products subject to change